

PRODUCT/PROCESS CHANGE NOTIFICATION

PCN AMS-AAS/14/8519 Dated 10 Jun 2014

Additional Back End capacity in Nantong Fujitsu for Signal conditioning products in TSSOP14 package (Analog and Audio Systems Division - AMS Group)

Table 1.	Change	Implementation	Schedule
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Forecasted implementation date for change	03-Jun-2014
Forecasted availability date of samples for customer	03-Jun-2014
Forecasted date for STMicroelectronics change Qualification Plan results availability	03-Jun-2014
Estimated date of changed product first shipment	09-Sep-2014

Table 2. Change Identification

Product Identification (Product Family/Commercial Product)	Signal conditioning products in TSSOP14 package
Type of change	Package assembly location change
Reason for change	To increase capacity and improve service to ST Customers
Description of the change	Progressing on the activities related to TSSOP14 manufacturing processes expansion, ST is glad to announce an additional production capacity (assembly, test & finishing) for signal conditioning products from Analog and Audio Systems Division (AAS Division) assembled in TSSOP14 package. For reference, production in Nantong Fujitsu for AAS Division is already running since 2008 for signal conditioning products in TSSOP8 and since 2006 for logic products in TSSOP14. For sample requests, please make sure you enter a non-standard sample order with the PCN reference in the comment field.
Change Product Identification	Traceability code (see qualification report section for more information)
Manufacturing Location(s)	

Table 3. List of Attachments

Customer Part numbers list	
Qualification Plan results	

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Customer Acknowledgement of Receipt	PCN AMS-AAS/14/8519
Please sign and return to STMicroelectronics Sales Office	Dated 10 Jun 2014
Qualification Plan Denied	Name:
Qualification Plan Approved	Title:
	Company:
🗖 Change Denied	Date:
Change Approved	Signature:
Remark	

Name	Function
Ferri, Simone	Marketing Manager
Onetti, Andrea Mario	Product Manager
Bugnard, Jean-Marc	Q.A. Manager

DOCUMENT APPROVAL



PRODUCT/PROCESS CHANGE NOTIFICATION

PCN AMS-AAS/14/8519

Analog, MEMS and Sensor Group (AMS)

Additional Back End capacity in Nantong Fujitsu for Signal conditioning products in TSSOP14 package (Analog and Audio Systems Division)



TSSOP14





WHAT:

Progressing on the activities related to TSSOP14 manufacturing processes expansion, ST is glad to announce an additional production capacity (assembly, test & finishing) for signal conditioning products from Analog and Audio Systems Division (AAS Division) assembled in TSSOP14 package. For reference, production in Nantong Fujitsu for AAS Division is already running since 2008 for Signal conditioning products in TSSOP8 and since 2006 for logic products in TSSOP14.

Material	Current process	Modified process
Assembly location	ST Bouskoura (Morocco) / Amkor (Philippines)	Nantong Fujitsu (China)
Die attach	ABLEBOND 8390/ ABLESTICK 8601S25	ABLEBOND 8200T
Wire	Gold 1 mils / copper 1 mils	Gold 1mil
Lead frame	Copper	Copper
Molding compound	Shinetsu KMC 184-3 SUMITOMO G630AY	Hitachi CEL9210HFVL
Lead finishing	NiPdAu / NiPdAgAu	Sn

Samples of test vehicles products are available and other products samples will be available upon request.

WHY:

To increase capacity and improve service to ST Customers for the affected package.

HOW:

The change that covers Signal conditioning products packaged in TSSOP14 is qualified through attached qualification plan. Here below you'll find the details of qualification plan.

Qualification program and results:

The qualification program consists mainly of comparative electrical characterization and reliability tests. Please refer to Appendix 1 for all the details.

WHEN:

The production for Signal conditioning products is forecasted in July 2014. Production in Nantong Fujitsu for AAS Division is already running since 2008 for Signal conditioning products in TSSOP8 and since 2006 for Logic products in TSSOP14.



Marking and traceability:

Unless otherwise stated by customer specific requirement, the traceability of the parts assembled in Nantong Fujitsu will be ensured by marking on package and on label as per below description:

	Manufactur	ed under patents or patents pene	ding
ronics	PbFree MSL: X	n: COUNTRY Second level interconnect Bag sealed date: XX XXX XX Catergory: ECOPACK/Rohs	xx
sct	TYPE	Commercial product Finished good	
croelectron	Total Qty: Trace codes	-	
Ĭ	Marking MA		PP and TF code will change from CZ to GU
5	Bulk Id Numb	ber	
		Bar code	
	Please pro	wide the bulk Id for any inquiry	
	y temperature (esent if leadfree	el as per Jedec J–std-020C maximum temperature for reflow e component	v soldering)
	PP: assembly p		
		the year of assembly	
	WW: Week of LL1: lot numbe		
	WX: Diffusion		
		shing plant code	

Bulk ID number: 1: Product level (T for tested product) Y: last digit of the year P: Plant code WW: Week of labeling LOT: Sequential number for lot BOXX: Sequential number for box

The changes here reported will not affect the electrical, dimensional and thermal parameters keeping unchanged all information reported on the relevant datasheets.

There is as well no change in the packing process or in the standard delivery quantities.



Lack of acknowledgement of the PCN within 30 days will constitute acceptance of the change. After acknowledgement, lack of additional response within the 90 day period will constitute acceptance of the change (Jedec Standard No. 46-C).

In any case, first shipments may start earlier with customer's written agreement.



Qualification Report

General Information			
Product Line	:	0339, 0464	
Product Description	:	Quad op amps	
Commercial Product	:	LM339PT, TS974IPT	
Product division/BU	:	Analog and Audio system	
Package	:	TSSOP14	
Technology process	:	Bipolar, HF2CMOS	
Jedec MSL : 1		1	

Locations		
Wafer fab location	Ang Mo Kio (singapore) Catania (Italy)	
EWS plant location	Toa Payoh (singapore) Catania (Italy)	
Final test plant location:	Nantong fujitsu (China)	

DOCUMENT APPROVAL LIST

NAME	FUNCTION	DATE	VISA
Jean-Marc Bugnard	Quality Manager AMS Grenoble	28 th April 2014	
	Grenoble	26 April 2014	

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods. This report does not imply for STMicroelectronics expressly or implicitly any contractual obligations other than as set forth in STMicroelectronics general terms and conditions of Sale. This report and its contents shall not be disclosed to a third party without previous written agreement from STMicroelectronics.





1 **RELIABILITY and qualification evaluation overview**

1.1 Objectives

The aim of this report is to present the qualification plan of the reliability evaluations performed on LM339PT and TS974IPT (test vehicles) to qualify the production of TSSOP14 package produced in Nantong Fujitsu for Signal conditioning products (AAS Division).

These results will come in addition to the TSSOP8 signal conditioning and TSSOP14 Logic results as they have been qualified previously (PCN 2242 and 7092)

1.2 Conclusion

All results are inside ST specification and the plan to achieve qualification exercise is described in below sections.

TSSOP14 is already produced in Nantong Fujitsu since 2006 for Logic products which also belong to the Analog and Audio Systems Division (AAS). The aim of this document is to explain the additional qualification tests performed to add the production of signal conditioning products in TSSOP14 in Nantong Fujitsu.



2 DEVICES TRACABILITY

2.1 Wafer fabrication information

	TV1	TV2
Line	0339	0464
Wafer Fab location	Singapore	Singapore
FE process	Bipolar	HF2CMOS
Die size (µm)	1100x1090	1450x1410
Die thickness (µm)	280	280
Metallization	AlSiCu	AlSiCu
Passivation	Si N	Si N+PSG
Back side	Raw Silicon	Raw Silicon

3.1 <u>Test vehicle</u>

Lot#	Process/ Package	Product Line	Comments
1	Bipolar / TSSOP14	0339	
2	HF2CMOS / TSSOP14	0464	

Detailed results in below chapter will refer to P/N and Lot #.

3.2 Test plan and results summary

Tests	Conditions	Step	TV1	TV2		Comments	
		Line	0339	0464			
Die ori	Die oriented tests						
	Tj=125°C		Ta=125	Ta=125			
HTB	Vs=absolute max rating JESD22 A-108	500h	77				
Packag	Package oriented tests						
AC	Ta=121C P=2atm JESD22 A-102	96h	77	77			
	To 65/:4500	100cy	77	77			
ТМС	Ta=-65/+150C JESD22 A-104	500cy	77	77			
MSL	Baking (150°C) Moisture soak 3 IR reflow soldering	24h MSL1	22	22			



For reference, below results described the tests done previously for TSSOP8 signal conditioning qualification :

Tests	Conditions	Step	TV1	TV2	TV3	Comments	
		Line	0158	393	P2VA		
ESD	CDM		0/3	0/3	0/3		
Die ori	Die oriented tests						
	Tj=125°C		Ta=125	Ta=125	Ta=150		
HTB	Vs=absolute max rating	168h	0/78	0/78			
	JESD22 A-108	1000h	0/78	0/78			
Packag	Package oriented tests						
тнв	Ta=85C RH=85% Vs=nominal	168h	0/78	0/78	0/24		
	JESD22 A-101	1000h	0/78	0/78	0/24		
AC	Ta=121C P=2atm	168h	0/78	0/78			
	JESD22 A-102	240h	0/78	0/78			
Env	TMC +	100cy			0/50		
seq	AC	168h			0/50		
тмс	Ta=-65/+150C JESD22 A-104	100cy	0/78	0/78	0/50		
		500cy	0/78	0/78	0/50		
		1000cy	0/78	0/78			
	Baking (150°C)	24h	0/22	0/22	0/5	MSL 1	
MSL	Moisture soak	Jedec	0/22	0/22	0/5	passed	
	3 IR reflow soldering	260°C	0/22	0/22	0/5	pusseu	



For reference, the below results described the tests done previously for TSSOP14 Logic qualification :

MPA (Micro, Power, Analog) Group Voltage Regulator, Interface, Advanced logic & Power RF Quality & Reliability

REL-019W06

Reliability Evaluation Plan and Results on

NANTONG FUJITSU - TSSOP Package

Test	Conditions	S.S.	Requirement	Results	
PRECONDITIONING OF SMD DEVICES BEFORE TC/THB/PP	DRYNG 24H @ 125°C STORE 192H @ TA=30°C RH=60% IR 3 times @ Tmax= 260°C		Parameter deviation within spec. limits at end of preconditioning - go no go	No parameter deviation out of spec. limits at end of preconditioning	
H.T.S.	TA=150°C	77x3 Lot	Parameter deviation within spec. limits at 1000h	No parameter deviation out of spec. limits at 1000 hours	
T.H.B.	D.U.T. PRECONDITIONED TA=85°C – RH=85% Vbias	77x3 Lot	Parameter deviation within spec. limits at 1000h	No parameter deviation out of spec. limits at 1000 hours	
H.T.B.	TA=125°C – Vbias	77x3 Lot	Parameter deviation within spec. limits at 1000h	No parameter deviation out of spec. limits at 1000 hours	
PRESSURE POT	D.U.T. PRECONDITIONED TA=121°C – PA=2ATM	77x3 Lot	Parameter deviation within spec. limits at 168h	No parameter deviation out of spec. limits at 168 hours	
THERMAL CYCLES AIR TO AIR	D.U.T. PRECONDITIONED TA=-65°C TO 150°C 1 HOUR/CYCLE	77x3 Lot	Parameter deviation within spec. limits at 500cycles	No parameter deviation out of spec. limits at 500 cycles	
SMD MOISTURE INDUCED STRESS	DRYNG 24H @ 125°C STORE 192H @ TA=30°C RH=60% IR 3 times @ Tmax= 260°C	25x3 Lot	Parameter deviation within spec. limits at end of test	No parameter deviation out of spec. limits at end of test	

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4 Annexes

4.1 <u>Tests Description</u>

Test name	Description	Purpose				
Die Oriented						
HTB High Temperature Bias	The device is stressed in static or dynamic configuration, approaching the operative max. absolute ratings in terms of junction temperature and bias condition.	To determine the effects of bias conditions and temperature on solid state devices over time. It simulates the devices' operating condition in an accelerated way. The typical failure modes are related to, silicon degradation, wire-bonds degradation, oxide faults.				
Package Oriented	-					
AC autoclave TC Temperature Cycling	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature. The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity. To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal				
		displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.				
THB Temperature Humidity Bias	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance with electrical field applied, both electrolytic and galvanic corrosion are put in evidence.				

5 GLOSSARY

- ESD Electro Static Discharge
- ELFR Early Life Failure Rate
- GL Gate Leakage
- HTB High Temperature Bias
- HTRB High Temperature Reverse Bias
- HTS High Temperature Storage
- T.H.B. Temperature Humidity Bias
- T.C. Thermal Cycle
- P.P. Pressure Pot
- P.C. Preconditioning

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